

## **DESCRIPTION**

The IS281-4 and IS281-5GB are four channel optical isolators with each channel consists of an infrared emitting diode optically coupled to an NPN silicon photo transistor.

These devices belong to Isocom Compact Range of Optocouplers.

#### **FEATURES**

- Half Pitch 1.27mm
- High AC Isolation voltage 3000V<sub>RMS</sub>
- Wide Operating Temperature Range -55°C to 110°C
- Pb Free and RoHS Compliant
- UL Approval E91231 Package Code "THP4"

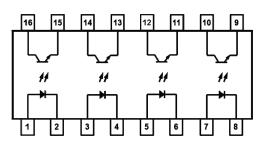
#### **APPLICATIONS**

- Hybrid Substrates with High Density Mounting
- Industrial System Controllers
- Measuring Instruments
- System Appliances

#### ORDER INFORMATION

 Available in Tape and Reel with 2000pcs per reel





## ABSOLUTE MAXIMUM RATINGS $(T_A = 25^{\circ}C)$

Stresses exceeding the absolute maximum ratings can cause permanent damage to the device.

Exposure to absolute maximum ratings for long periods of time can adversely affect reliability.

#### Input

Forward Current	50mA
Reverse Voltage	6V
Power dissipation	70mW

#### Output

Output Current	50mA
Collector to Emitter Voltage BV <sub>CEO</sub>	80V
Emitter to Collector Voltage BV <sub>ECO</sub>	7V
Power Dissipation	100mW

#### **Total Package**

Isolation Voltage	$3000V_{RMS}$
Total Power Dissipation	170mW
Operating Temperature	-55 to 110 °C
Storage Temperature	-55 to 150 °C
Lead Soldering Temperature (10s)	260°C

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# **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise specified)

## **INPUT**

Parameter	Symbol	Test Condition	Min	Тур.	Max	Unit
Forward Voltage	$V_{\rm F}$	$I_F = 20 \text{mA}$		1.2	1.4	V
Reverse Current	$I_R$	$V_R = 4V$			10	μΑ
Terminal Capacitance	$C_{t}$	$V_F = 0V$ , $f = 1KHz$		30	250	pF

## **OUTPUT**

Parameter	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector-Emitter Breakdown Voltage	BV <sub>CEO</sub>	$I_F = 0, I_C = 0.1 \text{mA}$	80			V
Emitter-Collector Breakdown Voltage	BV <sub>ECO</sub>	$I_F = 0, I_E = 10 \mu A$	7			V
Collector-Emitter Dark Current	$I_{CEO}$	$I_F=0,V_{CE}=48V$			100	nA

## **COUPLED**

Parameter	Symbol	Test Condition	Min	Тур.	Max	Unit
Current Transfer Ratio	CTR	$I_F = 5 \text{mA}, V_{CE} = 5 \text{V}$				%
		IS281-4 IS281-4GB	50 100		600 600	
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	$I_F = 8mA, I_C = 2.4mA$			0.4	V
Floating Capacitance	$C_{\mathrm{f}}$	$V_{CE} = 0V, f = 1MHz$		0.6	1	pF
Output Rise Time	t <sub>r</sub>	$V_{CE} = 10V$ ,		2	18	μs
Output Fall Time	$t_{\mathrm{f}}$	$Ic = 2mA,$ $R_{L} = 100\Omega$		3	18	
Turn-On Time	$t_{\rm ON}$	L		3		
Turn-Off Time	$t_{ m OFF}$			3		
Turn-On Time	$t_{\rm ON}$	$V_{CE} = 5V$ ,		2		
Turn-Off Time	$t_{ m OFF}$	Ic = $16\text{mA}$ , $R_L = 1.9\text{k}\Omega$		40		
Storage Time	$t_{\mathrm{S}}$	L		25		

## **ISOLATION**

Parameter	Symbol	Test Condition	Min	Тур.	Max	Unit
Input to Output Isolation Voltage	$V_{\rm ISO}$	RH = 40% - 60%, t = 1 min Note 1	3000			$V_{RMS}$
Input to Output Isolation Resistance	$R_{\rm ISO}$	RH = $40\%$ - $60\%$ , $V_{IO}$ = $500V$ Note 1	5x10 <sup>10</sup>	1x10 <sup>11</sup>		Ω

Note 1 : Measured with input leads shorted together and output leads shorted together.



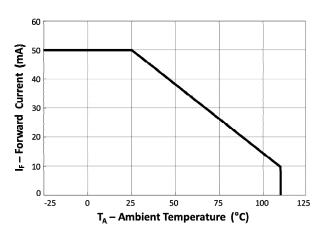


Fig 1 Forward Current vs T<sub>A</sub>

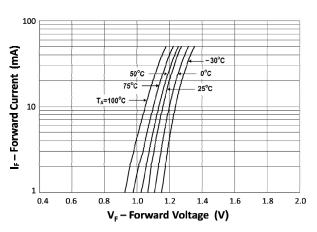


Fig 3 Forward Current vs Forward Voltage

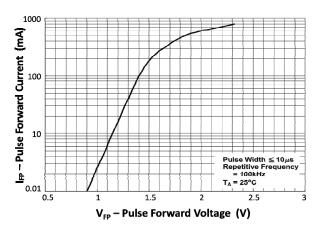


Fig 5 Pulse Forward Current vs Pulse Forward Voltage

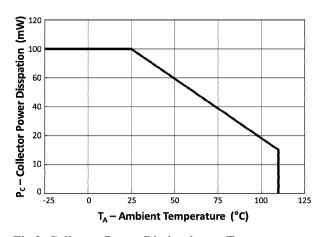


Fig 2 Collector Power Dissipation vs  $T_A$ 

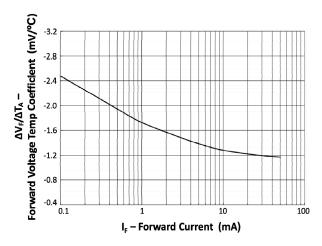


Fig 4 Forward Current Temperature Coefficient vs Forward Current

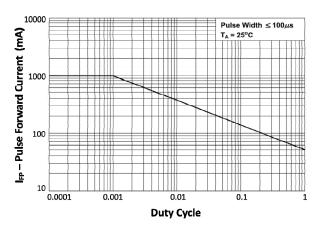


Fig 6 Pulse Forward Current vs Duty Cycle



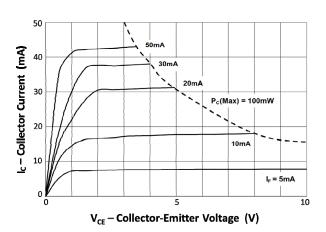


Fig 7 Collector Current vs Collector-Emitter Voltage

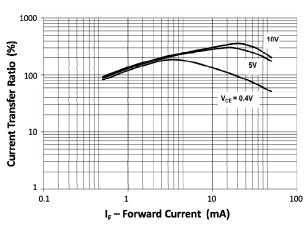


Fig 9 Current Transfer Ratio vs Forward Current

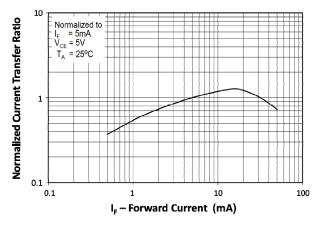


Fig 11 Normalized Current Transfer Ratio vs Forward Current

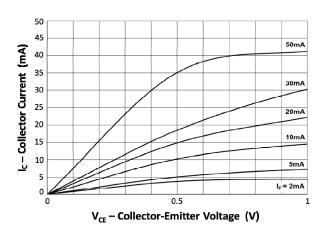


Fig 8 Collector Current vs Low Collector-Emitter Voltage

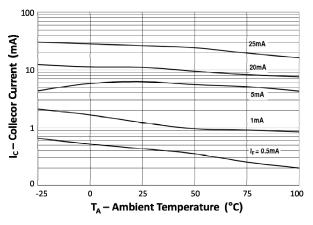


Fig 10 Collector Current vs T<sub>A</sub>

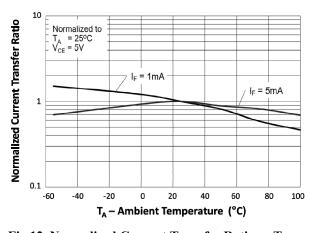


Fig 12 Normalized Current Transfer Ratio vs  $T_{\rm A}$ 



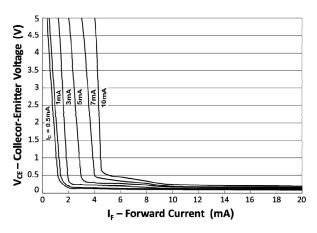


Fig 13 Collector-Emitter Voltage vs Forward Current

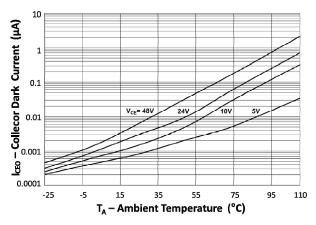


Fig 15 Collector Dark Curent vs TA

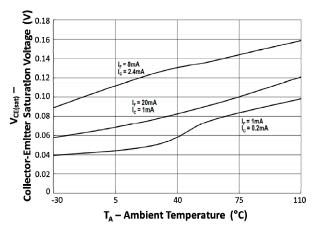


Fig 14 Collector-Emitter Saturation Voltage vs  $T_{\rm A}$ 

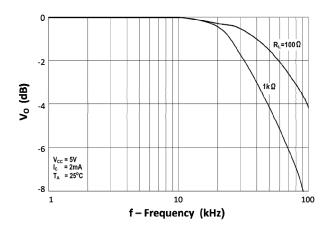


Fig 16 Frequency Response



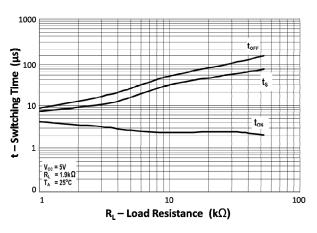


Fig 17 Switching Time vs Load Resistance

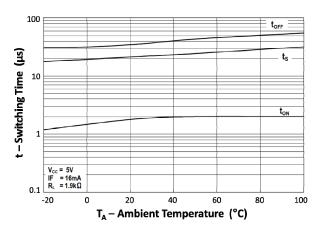
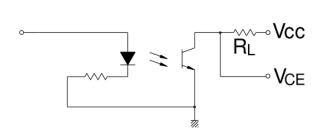
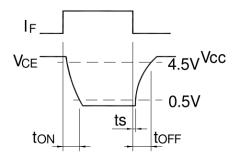


Fig 18 Switching Time vs  $T_A$ 





**Switching Time Test Circuit** 

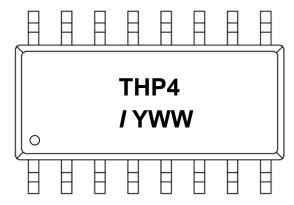


## **ORDER INFORMATION**

UL Approval				
After PN	PN Description Packing quantity			
None	IS281-4, IS281-4GB	Surface Mount Tape & Reel	2000 pcs per reel	

## **DEVICE MARKING**

Example: IS281-4



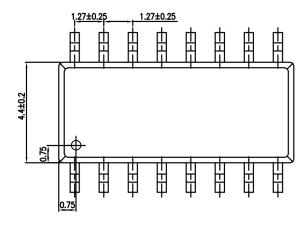
THP4 denotes Device Part Number

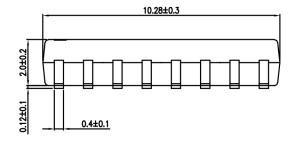
denotes Isocom

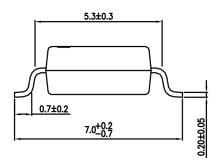
Y denotes 1 digit Year code WW denotes 2 digit Week code



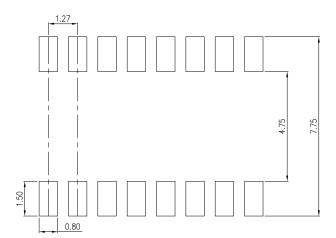
## **PACKAGE DIMENSIONS (mm)**





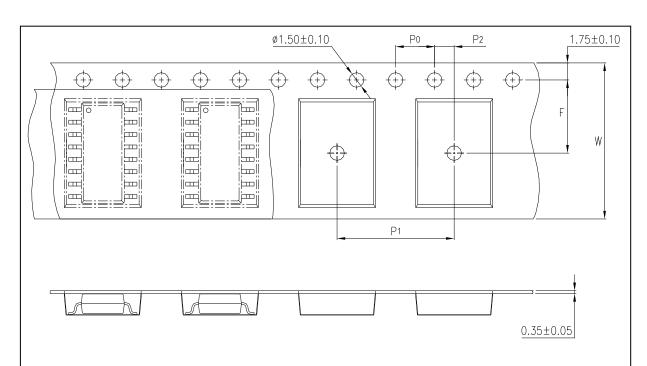


## **RECOMMENDED SOLDER PAD LAYOUT (mm)**





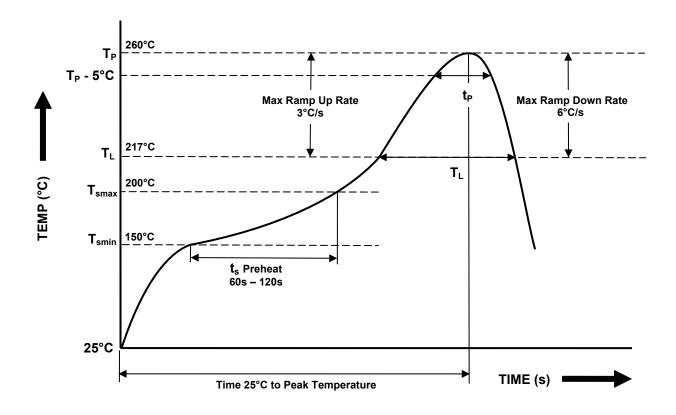
## **TAPE AND REEL PACKAGING**



Description	Symbol	Dimension mm (inch)
Tape Width	W	16 ± 0.3 (0.63)
Pitch of Sprocket Holes	P <sub>0</sub>	4 ± 0.1 (0.15)
Distance of Compartment to Sprocket Holes	F	7.5 ± 0.1 (0.295)
	P <sub>2</sub>	2 ± 0.1 (0.079)
Distance of Compartment to Compartment	P <sub>1</sub>	12 ± 0.1 (0.47)



# IR REFLOW SOLDERING TEMPERATURE PROFILE One Time Reflow Soldering is Recommended. Do not immerse device body in solder paste.



Profile Details	Conditions
$ \begin{array}{l} \textbf{Preheat} \\ \textbf{- Min Temperature } (T_{SMIN}) \\ \textbf{- Max Temperature } (T_{SMAX}) \\ \textbf{- Time } T_{SMIN} \ to \ T_{SMAX} \ (t_s) \end{array} $	150°C 200°C 60s - 120s
$\begin{tabular}{ll} \textbf{Soldering Zone} \\ - & \mbox{Peak Temperature } (T_P) \\ - & \mbox{Time at Peak Temperature} \\ - & \mbox{Liquidous Temperature } (T_L) \\ - & \mbox{Time within } 5^{\circ}\mbox{C of Actual Peak Temperature } (T_P - 5^{\circ}\mbox{C}) \\ - & \mbox{Time maintained above } T_L \ (t_L) \\ - & \mbox{Ramp Up Rate } (T_L \ \mbox{to } T_P) \\ - & \mbox{Ramp Down Rate } (T_P \ \mbox{to } T_L) \\ \end{tabular}$	260°C 10s max 217°C 30s max 60s - 100s 3°C/s max 6°C/s max
Average Ramp Up Rate (T <sub>smax</sub> to T <sub>P</sub> )	3°C/s max
Time 25°C to Peak Temperature	8 minutes max



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